NSN 5961-00-497-3860

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-497-3860
Inclosure Material:
Plastic
Overall Length:
0.375 inches
Overall Height:
0.190 inches
Overall Width:
0.400 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Base
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
200.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
5.00 amperes drain current nanoamperes
Power Rating Per Characteristic:
1.3 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
110.0 degrees celsius case
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0